

**AMENDMENTS TO THE SPECIFICATION**

**At page 1, just before "FIELD OF THE INVENTION," please add the following new paragraph:**

This application is a divisional of U.S. patent application number 09/808,114, filed March 15, 2001, and entitled "TECHNIQUE TO MITIGATE SHORT CHANNEL EFFECTS WITH VERTICAL GATE TRANSISTOR WITH DIFFERENT GATE MATERIALS," the entirety of which is hereby incorporated by reference herein.